NSN 5961-01-042-2129

Unitized Semiconductor Devices - Page 1 of 1



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IOINT	Flectronic	Device Fr	naineerina	Council	ledec/case	Cuttine	Jesignation:

To-116

Component Name And Quantity:

4 transistor

Semiconductor Material:

Silicon all semiconductor

Voltage Rating In Volts Per Characteristic:

60.0 collector-to-emitter, substaining voltage, base open-circuited 1st transistor

Current Rating Per Characteristic:

600.00 milliamperes all primaries all semiconductor

Special Features:

Dual-in-line; case 632; internal junction configuration semiconductor npn

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0